



HIGH-VOLTAGE, HIGH-CURRENT 7 DARLINGTON ARRAYS

These high-voltage, high-current Darlington transistor arrays comprise seven NPN Darlington pairs on a common monolithic substrate. All units feature open collector outputs and integral suppression diodes for inductive loads. Peak currents of 600 mA can be withstood, making them ideal for driving tungsten filament lamps.

The L 201 is a general-purpose array wich may be used with DTL, TTL, PMOS, CMOS, etc. It is pinned with inputs opposite outputs to facilitate circuit board layout and is priced to compete directly with discrete transistor alternatives.

The L 202 was specifically designed for use with 14 to 25V PMOS devices. Each input has a Zener diode and resistor in series in order to limit the input current to a safe value.

The L203 has a series base resistor to each Darlington pair allowing operation directly with TTL or CMOS operating at a supply voltage of 5V.

The L204 has a series base resistor to each Darlington pair, allowing operation directly with PMOS or CMOS utilizing supply voltage of 6 to 15V.

In all cases, the individual Darlington pair collector current rating is 500 mA. However, outputs may be paralleled for higher load current capability. The devices are supplied in a 16-lead dual in-line plastic package with copper frame.

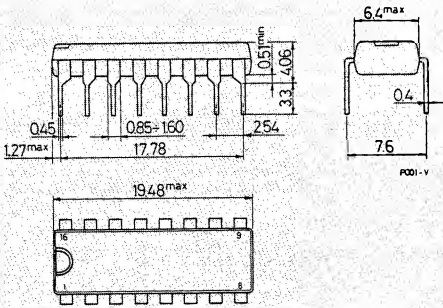
ABSOLUTE MAXIMUM RATINGS

V_i	Input voltage (for L 202, L 203 and L 204)	30	V
V_o	Output voltage (collector-emitter)	50	V
$V_{CEO(sus)}$	Collector-emitter sustaining voltage	36	V
I_C	Collector current	500	mA
I_B	Base current (for L 201 only)	25	mA
P_{tot}	Total power dissipation at $T_{amb} = 25^{\circ}C$	1.8	W
T_{op}	Operating junction temperature	-25 to 150	$^{\circ}C$
T_{stg}	Storage temperature	-55 to 150	$^{\circ}C$

ORDERING NUMBERS: L201B, L203B
L202B, L204B

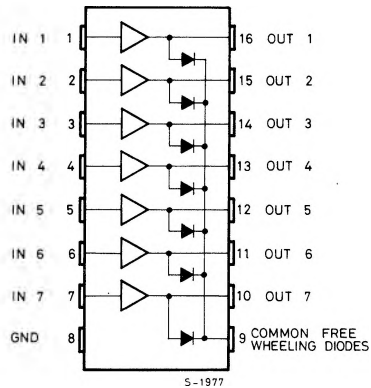
MECHANICAL DATA

Dimensions in mm



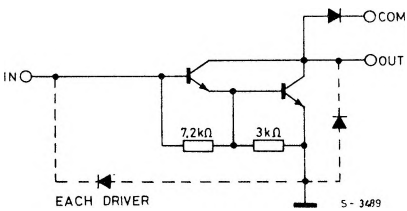


CONNECTION DIAGRAM (top view)

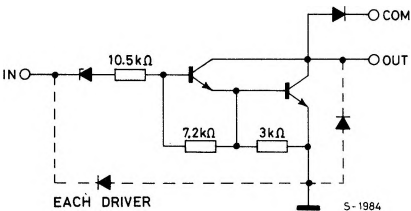


SCHEMATIC DIAGRAM

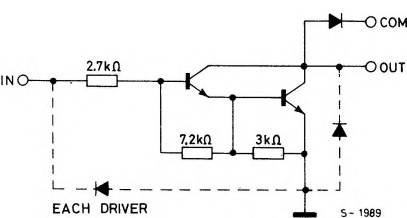
For L 201



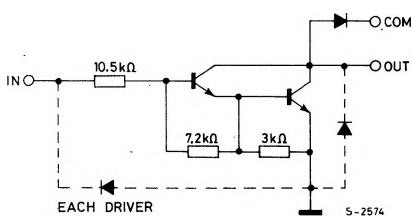
For L 202



For L 203



For L 204





THERMAL DATA

$R_{th\ j-amb}$	Thermal resistance junction-ambient	max.	70 °C/W
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ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

Parameter	Test conditions	Min.	Typ.	Max.	Unit	Fig. No.
I_{CEX} Collector cutoff current	for L 201 $V_{CE} = 50V$		0.2	3	μA	1
	for L 202 $V_{CE} = 50V$ $V_i = 7V$		0.2	3	μA	2
	for L 203, L 204 $V_{CE} = 50V$ $I_i = 0$		0.2	3	μA	1
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_C = 350\text{ mA}$ $I_B = 500\text{ }\mu A$		1.25	1.6	V	3
	$I_C = 200\text{ mA}$ $I_B = 350\text{ }\mu A$		1	1.3	V	
	$I_C = 100\text{ mA}$ $I_B = 250\text{ }\mu A$		0.85	1.1	V	
I_i Input current	for L 202 $V_i = 17V$		0.75	1.3	mA	5
	for L 203 $V_i = 3.85V$		0.9	1.35	mA	
	for L 204 $V_i = 5V$		0.35	0.5	mA	
	$V_i = 12V$		1.1	1.45	mA	
$I_{C(off)}$	$V_{CE} = 50V$ $I_i = 25\text{ }\mu A$			25	μA	4
V_i Input voltage	for L 202 $I_C = 300\text{ mA}$ $V_{CE} = 2V$		10.5	13	V	7
	for L 203 $I_C = 300\text{ mA}$ $V_{CE} = 2V$		1.8	3	V	
	$I_C = 250\text{ mA}$ $V_{CE} = 2V$		1.7	2.4	V	
	for L 204 $V_{CE} = 2V$ $I_C = 200\text{ mA}$		4.5	6	V	
	$V_{CE} = 2V$ $I_C = 350\text{ mA}$		5	8	V	
h_{FE} DC current gain (for L 201 only)	$I_C = 350\text{ mA}$ $V_{CE} = 2V$	1000	3000		—	3
I_R Parallel diode reverse current	$V_R = 50V$		0.5	50	μA	6
V_F Parallel diode forward voltage	$I_F = 350\text{ mA}$		1.4	2	V	8
t_{PLH} Turn-on delay time	$0.5\text{ }V_i$ to $0.5\text{ }V_o$			5	μs	—
t_{PHL} Turn-off delay time	$0.5\text{ }V_i$ to $0.5\text{ }V_o$			5	μs	—



TEST CIRCUITS

Fig. 1 - For L 201, L 203
and L 204

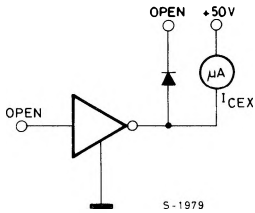


Fig. 2 - For L 202

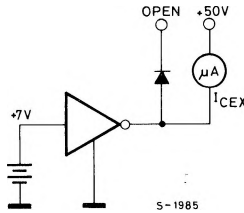


Fig. 3 - For L 201, L 202,
L 203 and L 204

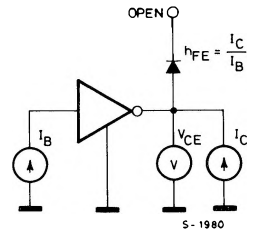


Fig. 4 - For L 201, L 202,
L 203 and L 204

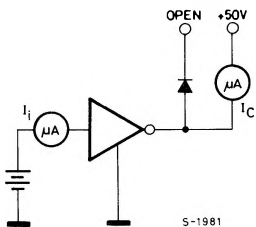


Fig. 5 - For L 202, L 203,
and L 204

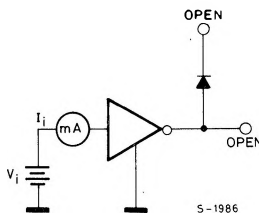


Fig. 6 - For L 201, L 202,
L 203 and L 204

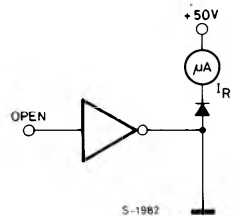


Fig. 7 - For L 202, L 203,
and L 204

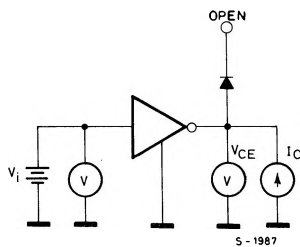
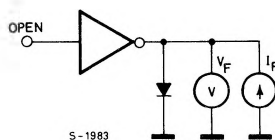


Fig. 8 - For L 201, L 202,
L 203 and L 204



APPLICATION CIRCUITS

PMOS to load
(L 202 and L 204)

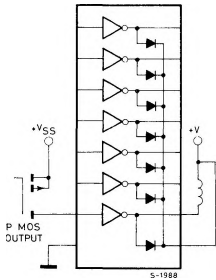


Fig. 9 - DC current gain, vs. collector current (for L 201)

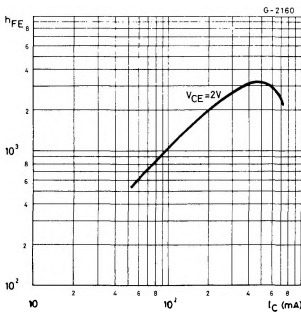
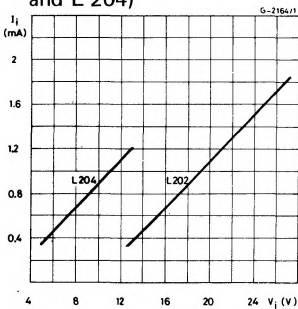


Fig. 12 - Input current vs. input voltage (for L 202 and L 204)



Buffer for high current load
(L 203 and L 204)

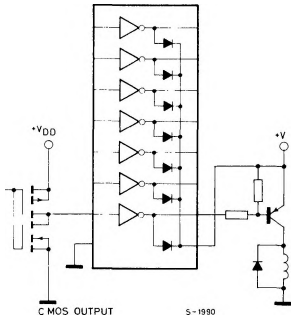


Fig. 10 - Collector current vs. collector emitter saturation voltage

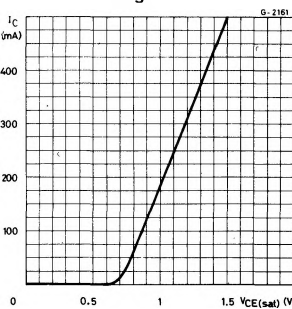
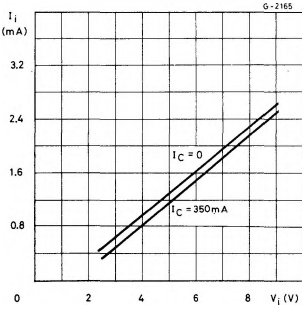


Fig. 13 - Input current vs. input voltage (L 203)



TTL to load (L 203)

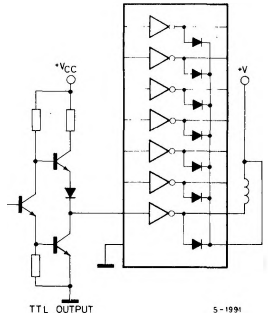


Fig. 11 - Peak collector current as a function fo duty cycle and number of outputs

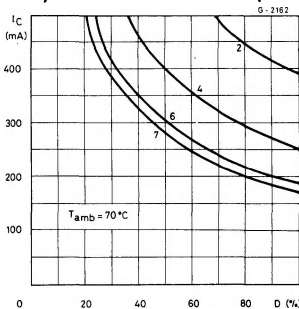


Fig. 14 - Power rating chart

